

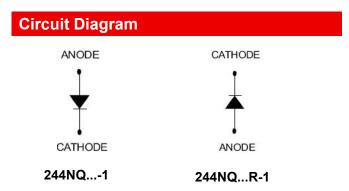
244NQ.../R-1

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244NQ035(R)-1/244NQ040(R)-1/244NQ045(R)-1 SCHOTTKY RECTIFIER





The top side is terminal, the bottom side is base plate.

Features

- 125℃ T_J operation
- Unique high power, Half-Pak module
- Replaces three parallel DO-5' S
- Easier to mount and lower profile than DO-5' S
- High purity, high temperature epoxy encapsulation for enhanced
- mechanical strength and moisture resistance
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Base plate: Nickel plated; Terminals: Nickel plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition		Max.	Units
Peak Repetitive Reverse Voltage	V _{RRM}	-	35	244NQ035(R)-1	
Working Peak Reverse Voltage	V _{RWM}		40	244NQ040(R)-1	V
DC Blocking Voltage	VR		45	244NQ045(R)-1	
Average Forward Current	I _{F(AV)}	50% duty cycle @Tc =75°C, rectangular wave form		240	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	4560		А
Non-Repetitive Avalanche Energy	E _{AS}	TJ=25℃,I _{AS} =40A,L=0.34mH	270		mJ
Repetitive Avalanche Current	lar	Current decaying linearly to zero in 1 μ sec Frequency limited by T _J max. V _A =1.5×V _R typical	40		A

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 240A, Pulse, T _J = 25 °C	0.49	0.55	V
	• • • •	@ 480A, Pulse, T _J = 25 °C	0.56	0.73	•
	V _{F2}	@ 240A, Pulse, T _J = 100°C	0.45	0.52	V
	V F2	@ 480A, Pulse, T _J = 100 °C	0.51	0.72	v
Reverse Current*	I _{R1}	$@V_R$ = rated $V_R T_J$ = 25 °C	3.4	20	mA
	I _{R2}	$@V_R$ = rated $V_R T_J$ = 125 °C	243	3500	mA
Junction Capacitance	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	8580	10300	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

* Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification		Units
Junction Temperature	TJ	-	-55 to +125		°C
Storage Temperature	T _{stg}	-	-55 to +125		°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	0.25		°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ hetacs}$	Mounting surface, smooth and greased	0.07		°C/W
Mounting Torque	т	Non-lubricated threads	Mounting Torque	23(min) 29(max)	Kalom
Mounting Torque	Τ _M	Non-Iubricated tilleads	Terminal Torque	35(min) 46(max)	Kg-cm
Approximate Weight	wt	-	36		g
Case Style	PRM1-1				

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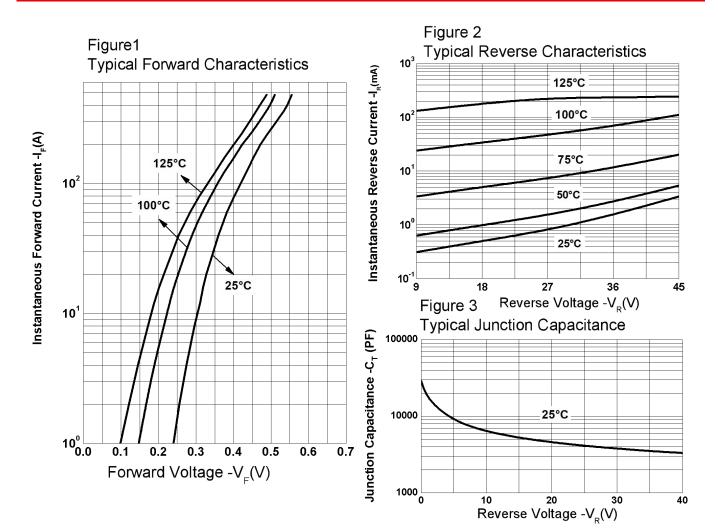


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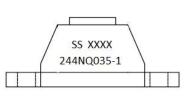
Ratings and Characteristics Curves



Ordering Information

Device	Package	Shipping	
244NQ1	PRM1-1(Pb-Free)	27pcs/ box	

Marking Diagram



Where XXXX is YYWW

1st row SS YYWW 2nd row 244NQ035-1 SS = SS YY = Year WW = Week

- Week

Cautions: Molding resin Epoxy resin UL:94V-0

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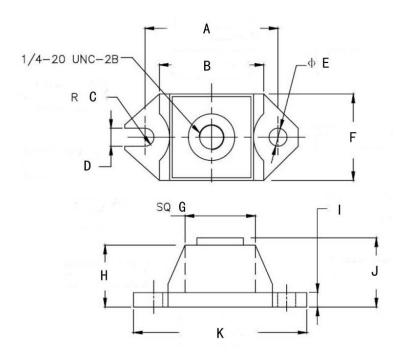


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Mechanical Dimensions PRM1-1 (Inches/Millimeters)



SYMBOL	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
A	29.35	30.95	1.155	1.219	
В	24.77	26.04	0.975	1.026	
С	1.79	2.19	0.070	0.087	
D	3.73	4.24	0.146	0.167	
E	3.73	4.24	0.146	0.167	
F	18.42	19.69	0.725	0.775	
G	18.55	19.55	0.730	0.770	
н	13.59	14.47	0.535	70.500	
I	3.05	3.90	0.120	0.154	
J	14.87	15.87	0.585	0.625	
К	38.61	39.62	1.520	1.560	

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